

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of :
Beom-jun JIN et al. : Attn: Applications Branch
Serial No. (New) : Attorney Docket No. SEC.872D
Filed: October 16, 2003 :
For: SEMICONDUCTOR MEMORY DEVICE HAVING MULTI-LAYERED
STORAGE NODE CONTACT PLUG AND METHOD FOR FABRICATING
THE SAME

PRELIMINARY AMENDMENT

U.S. Patent and Trademark Office
2011 South Clark Place
Customer Window, **Mail Stop Patent Application**
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

Sir:

Preliminary to the examination of the above-identified application, the following
amendments and remarks are submitted:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on
page 3 of this paper.

Remarks/Arguments begin on page 6 of this paper.